

# UK Activities on pixels.

(Previous report at Frascati, Dec 2009)

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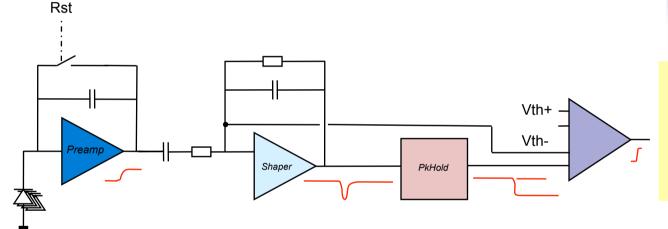
#### Overview

- Brief Reminder of the concept:
- Work since Frascati:
  - Discussions with Pisa (March)
  - Material Budget
  - Geometries: Long Barrel Lampshade
- To Do... (a long list):
  - Chip
  - Support
  - Physics studies



# TPAC-style sensor for SuperB

- Deep p-well pixel design (derived from TPAC).
- On pixel preamp, shaper, peak hold.



The PeakHold keeps data until pixel can be readout/reset. ~12µW static power per pixel.

NMOS

TRANSISTOR

NWELL

DIODE

SUB

CONN

INCIDENT

PMOS

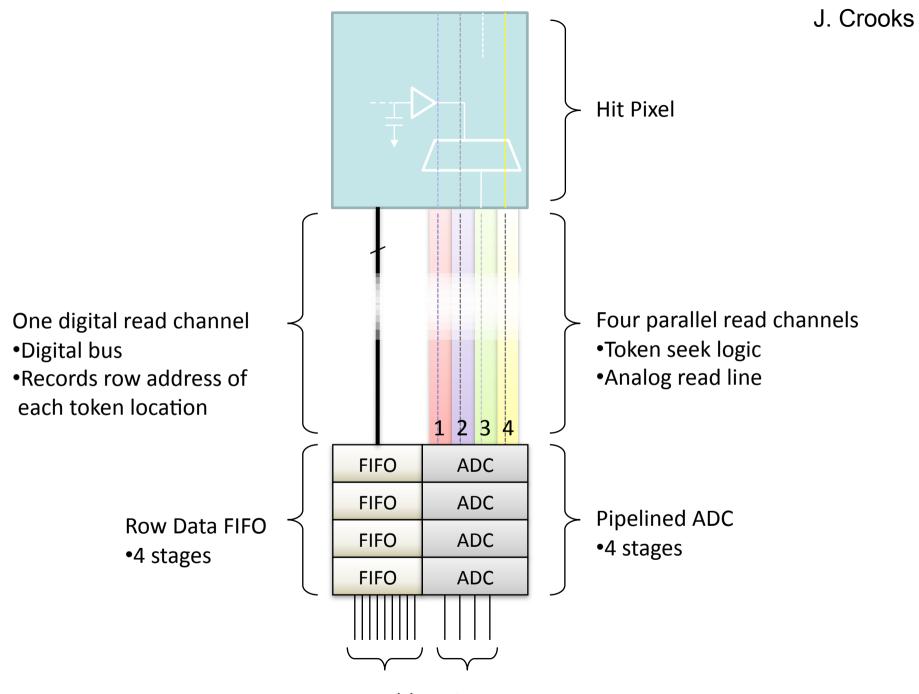
TRANSISTOR CONN

EPITAXIAL LAYER

NWELL DEEP PWELL

WELL

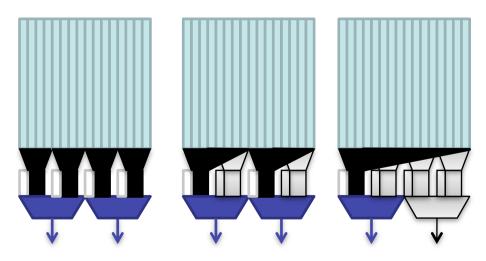
- Token seek readout logic.
- 5bit Ramp ADC per column of pixels to provide some dE/dx information (need to evaluate the impact from this).

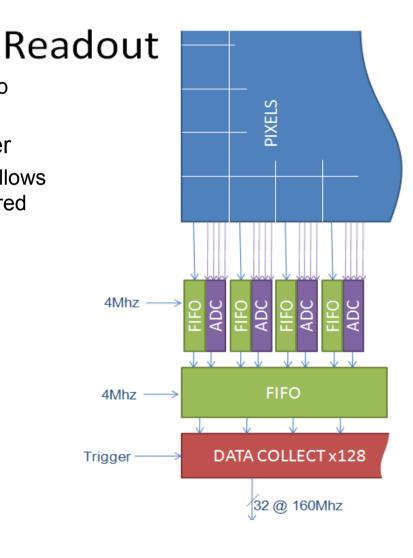


Row Addr Hit Data



- Data rates from Layer 0 are very high
  - Consider an on-chip FIFO with external veto /trigger to reduce data volume
- Data rates from outer layers are much lower
  - Consider a column multiplexer circuit that allows ADCs to be shared while others are powered down in outer layers
  - Could use the same ASIC design with less connections (bonds) for outer layers?

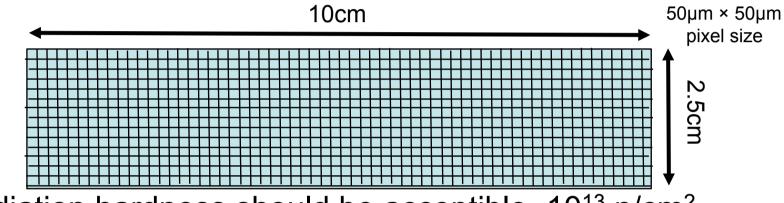






#### Sensor module for SuperB

- Alter layout of the chip: (4×2.5cm<sup>2</sup> chip stitched together)
  - 1 module = a 10cm × 2.5 cm × 50µm sensor.



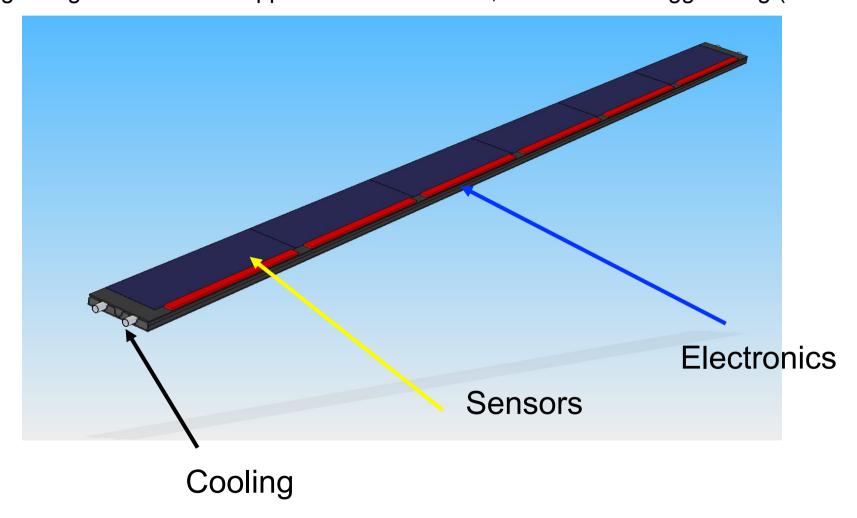
Radiation hardness should be acceptible~10<sup>13</sup> n/cm<sup>2</sup>.

- 10 W power per module: < 5KW per 6 layer SVT.</p>
  - Requires active cooling.
  - Ramifications for:
    - Material Budget.
    - Utility hook-up (cooling/power/readout).
      Annecy March 09



#### **Stave Drawings**

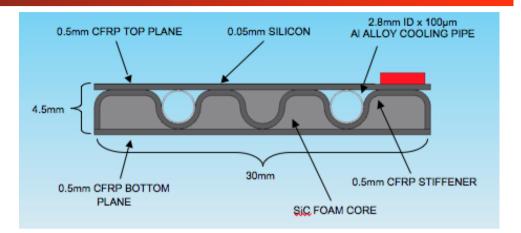
Concept: use staves as a basic unit for assembly of the detector. Design a rigid stave to be supported from the ends, with minimal saggital sag (250um).





# Material Budget: Some initial studies

- Made first go at Stave structure
- Sandwich
  - Silicon 50 microns
  - Carbon Fiber
  - Silicon Carbide Foam
  - Aluminum Cooling pipes
- Current Material budget
  - 1.1 % per stave
  - Dominated by carbon fiber
- Very conservative design
  - Will be reduced after more



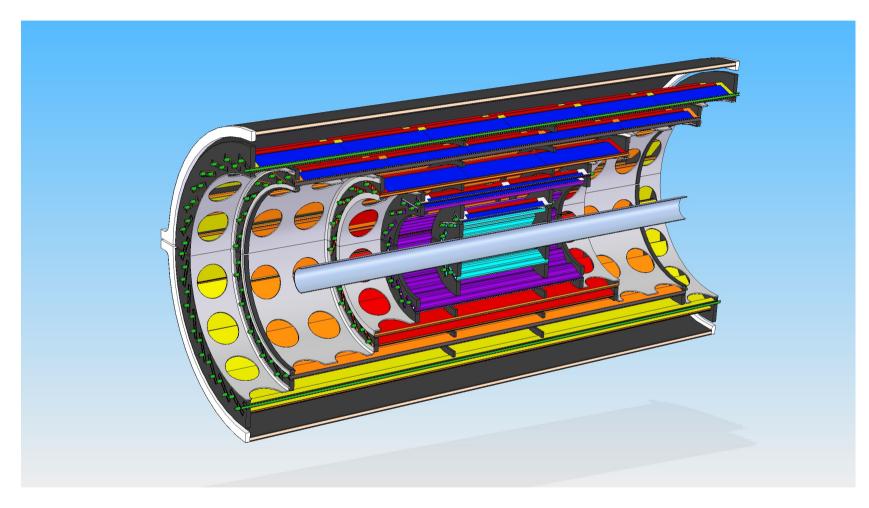
Material	Radiation length, D <sub>0</sub> (mm)	%X <sub>0</sub>
CFRP	240	0.730
Al Alloy	89	0.069
SIC FOAM	1000	0.181
Silicon	94	0.053
Coolant (Water)	360	0114
	TOTAL	1.146%



(Material thickness averaged over section of stave)



#### **Mechanical Layout**



The Lamp-Shade geometry can be adapted from this design – need to try barrel vs LS optimization studies to quantify any gains.



### Costs

- Expect a yield of ~60%
  - This is based on previous experience with this foundry.
  - Expect sensor cost of \$0.5M / 330K€.

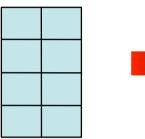
Total Surface		1	$m^2$	1
Sensor Size	x	100	mm	100
	x	25	mm	25
sensor/wafer		5		5
Total good sensors needed		400		400
yield		20%		60%
Total number of sensors needed		2,000		667
Total number of wafers		400		134
Cost/wafer		\$ 3,750		\$ 3,750
Wafer cost		$1.5M (1M\epsilon)$		$0.5M (0.33M\epsilon)$
$\operatorname{Cost}/cm^2$		\$ 150		\$ 50
NRE (set-up-costs)		\$ 190,000		\$190,000

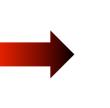


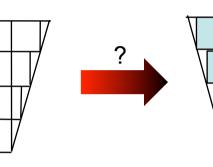
- Marcel Stanitzki, Fergus Wilson, AB recently visited Pisa.
  - Extremely useful meeting many ideas exchanged.
    - Concepts for lighter support structure.
    - Geometry of the detector, and how to realise this.
    - Visited the Pisa facilities to see the status of their R&D.
  - Detailed list of things to investigate between now and the end of the TDR period (see later).
  - Outlined a path for tighter collaboration between UK and Italian efforts.



- Work on the chip:
  - How can we make LS end modules?

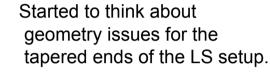






Easy to fabricate

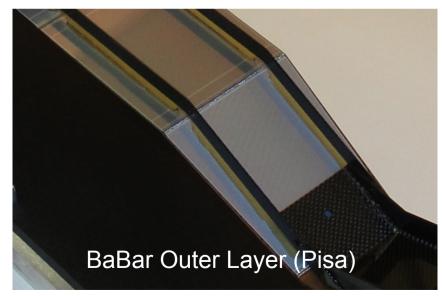
Not so clear cut



Bus cable is a solvable issue

The CMOS structure – especially with stitching is a little more complicated...

- While it is easy to make trapezoidal sensors with strips; this is harder for INMAPS.
- Can make a variant on Rectangular geometries.



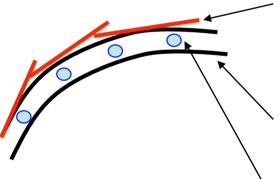
Easy



- Work on the Chip:
  - Radiation hardness.
  - Power consumption vs. hit rate.
  - Signal resolution as a fn of incident angle.
  - Usefulness of dE/dx measurement from 50um of silicon (Re: ADC).
  - Power distribution/signal bus over 30cm (utilities issue) & do we need coupling capacitors over this length.
  - Cooling over 30cm (utilities issue)



- Work on the mechanics: L0 off bellows, L1-N off cryostat
  - How much material in the bus.
  - What is the material budget for inner/outer layers (between 0.2 and 1.14%).
    - Half shell space-frame geometry with overlapping sensors to minimize material budget?



Retain pinwheel for the silicon sensors (50um thick).

Superstructure would support sensors at ends (struts in the middle as/if needed).

Cooling infrastructure would support the sensor along z (into page).

What would the material budget of this be vs. stave design?



- Work on physics studies:
  - Study low level information on particle tracking: d<sub>0</sub>, ...
  - Low momentum tracking performance
  - Affect on  $\theta_{\rm C}$  resolution in DIRC from material.
  - Study a number of modes to see how each design choice affects the potential output:
    - π<sup>+</sup>π<sup>-</sup>, π<sup>0</sup>π<sup>0</sup>, D\*X (soft pions), D-mixing (at 4S and threshold), τν &/ Kvv [aim to define Barrel and LS geometries in Fast Sim to check signal performance]
  - Study the material budget as a function of θ, etc. ... using particle gun modes of FastSim and Bruno.
  - Physics benefit of r=1.3 vs. r=1cm.



# Summary

- Already had some good ideas to go away and think about as possible variant concepts on the support.
  - A natural to tie in with work from Filippo Bosi.
- Now need to knuckle down and do some more work...
- Aim to define a long barrel and lampshade design for signal studies in the simulation programmes as soon as we define the amount of bus material.
  - As we understand the mechanics of the space-frame geometry, will put a geometry together on that as well.
- A lot of work to do!